PARA LIGHT NANJING ELECTRONICS CO., LTD.
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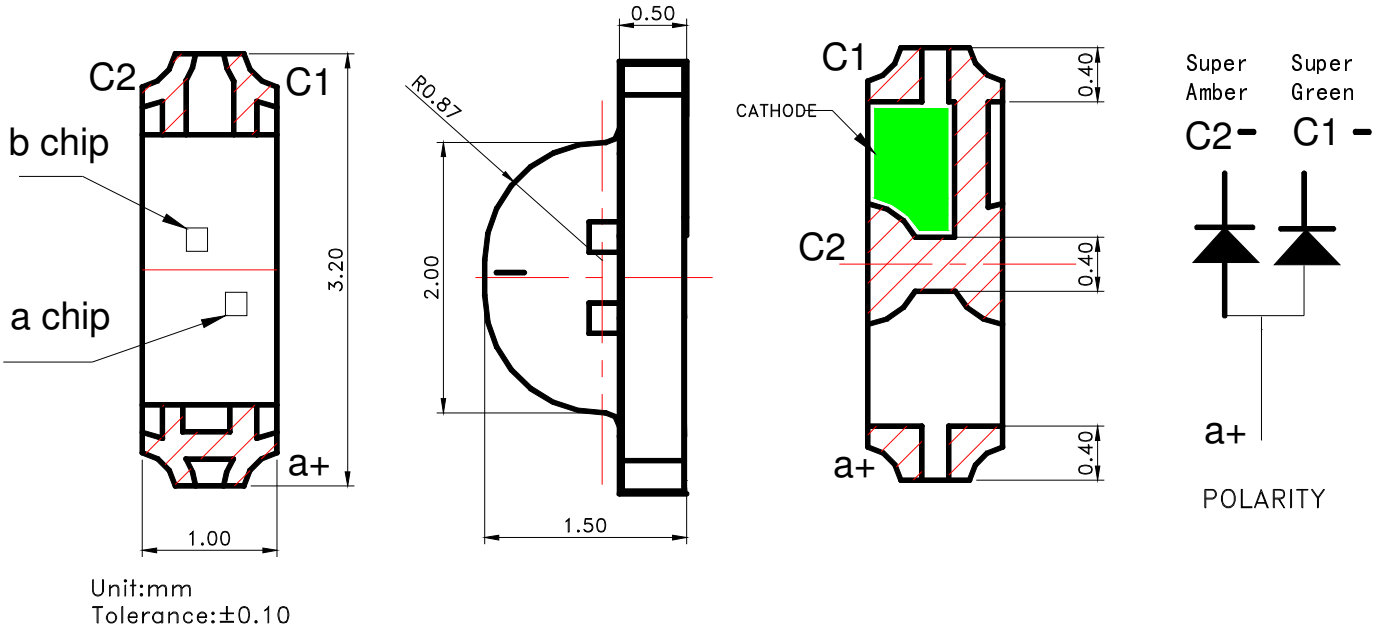
DATA SHEET

PART NO.: SZS115KGKFCT

REV: A / 4

CUSTOMER'S APPROVAL : _____ DCC : _____

● PACKAGE OUTLINE DIMENSIONS



Unit:mm
Tolerance:±0.10

Notes:

1. a chip: Super Green; b chip: Super Amber.
2. All dimensions are in millimeters.
3. Tolerance is ± 0.1mm (.004") unless otherwise noted.

● Features

- ∗ Dual color, common anode, side view Chip LED.
- ∗ Package in 8mm tape on 7" diameter reels.
- ∗ Compatible with automatic Pick & Place equipment.
- ∗ Compatible with Reflow soldering and Wave soldering processes.
- ∗ EIA STD package.
- ∗ I.C. compatible.
- ∗ Pb free product.
- ∗ Meet RoHS Green Product.

Chip Materials

chip	Light Color	Dice Material	Lens Color
a	KG: Super Green	AlInGaP	White Clear
b	KF: Super Amber	AlInGaP	

Absolute Maximum Ratings(Ta=25℃)

Symbol	Parameter	Rating		Unit
		Super Green	Super Amber	
P_D	Power Dissipation	60	75	mW
I_{PF}	Peak Forward Current (1/10 Duty Cycle, 0.1ms Pulse Width)	60	80	mA
I_F	Continuous Forward Current	30	30	mA
-	De-rating Linear From 25℃	0.25	0.25	mA/℃
V_R	Reverse Voltage	5	5	V
ESD	Electrostatic Discharge Threshold(HBM)Note A	2000		V
Topr	Operating Temperature Range	-40 ~ +85		℃
Tstg	Storage Temperature Range	-40 ~ +85		℃
-	Wave Soldering Condition (Two times Max.)	260 (for 5 seconds)		℃
-	Infrared Soldering Condition (Two times MAX.)	240 (for 5 seconds)		℃

Note A:

HBM: Human Body Model. Seller gives no other assurances regarding the ability of to withstand ESD

Electro-Optical Characteristics(Ta=25℃)

Parameter		Symbol	Super Green	Super Amber	Unit	Test Condition
Luminous Intensity	Min.	IV	25.0	40.0	mcd	IF=20mA
	Typ.		50.0	80.0		
Viewing Angle	，Typ.	2θ 1/2	130		deg	Note 2
Peak Wavelength	Typ.	λp	571	611	nm	Measurement @Peak
Dominant Wavelength	Typ.	λd	570	605	nm	IF=20mA
Spectral Line Half-Width	Typ.	Δλ	15	17	nm	
Forward Voltage	Typ.	VF	2.05	2.0	V	IF =20mA
	Max.		2.4	2.4		
Reverse Current	Max.	IR	10		μA	VR = 5V

Notes:

1. Luminous intensity is measured with a light sensor and filter combination that proximities the CIE eye-response curve.
2. θ 1/2 is the off-axis angle at which the luminous intensity is half the axial luminous intensity.
3. The dominant wavelength λ d is derived from the CIE chromaticity diagram and represents the single wavelength which defines the color of the device.
4. Caution in ESD :
   Static Electricity and surge damages the LED. It is recommended use a wrist band or anti-electrostatic glove when handling the LED. All devices, equipment and machinery must be properly grounded.
5. Major standard testing equipment by "Instrument System" Model : CAS140B Compact Array Spectrometer and "KEITHLEY" Source Meter Model : 2400.

• Typical Electro-Optical Characteristics Curves

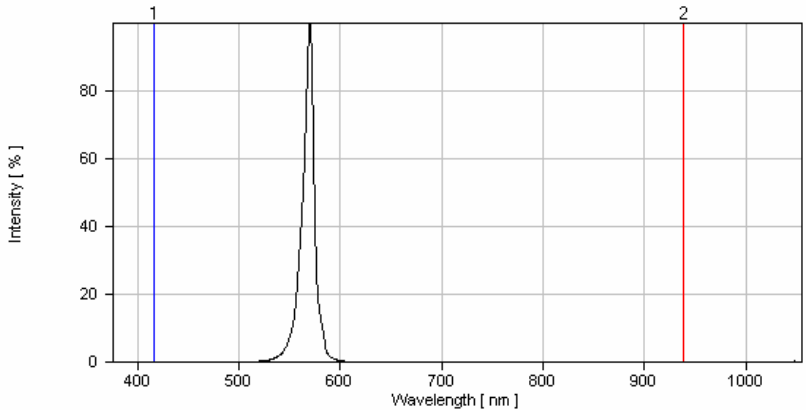


Fig.1 Super Green Relative Intensity vs. Wavelength

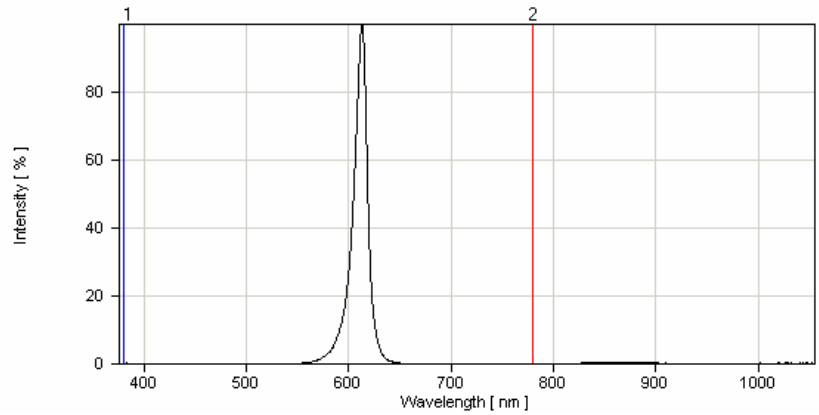


Fig.2 Super Amber Relative Intensity vs. Wavelength

● Super Green Typical Electro-Optical Characteristics Curves

(25℃ Ambient Temperature Unless Otherwise Noted)

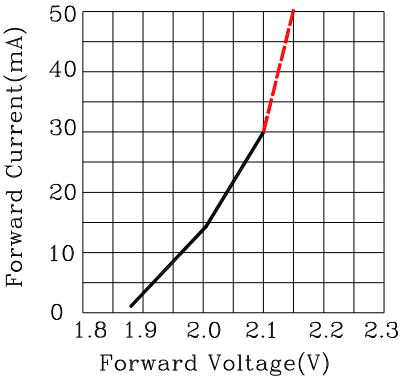


Fig.2 Forward Current vs.Forward Voltage

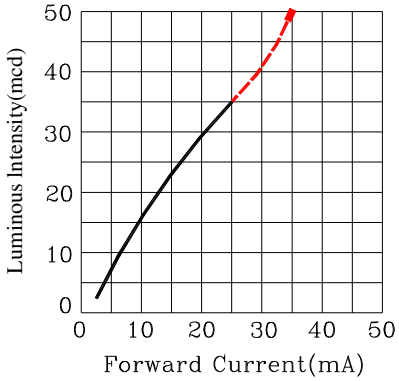


Fig.3 Luminous Intensity vs.Forward Current

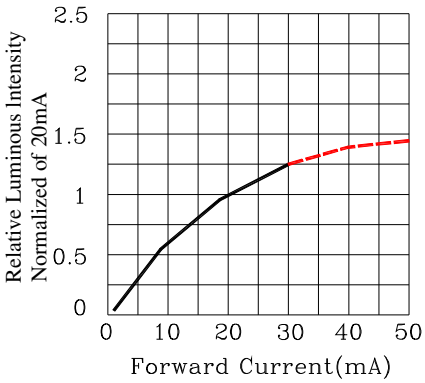


Fig.4 Relative Luminous Intensity vs.Forward Current

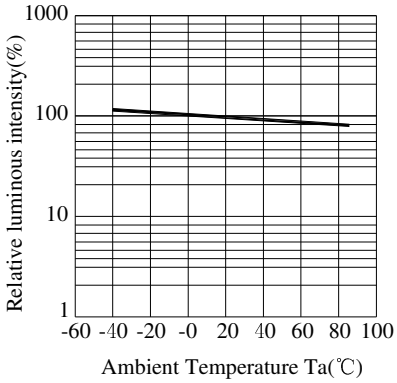


Fig.5 Luminous Intensity vs.Ambient Temperature

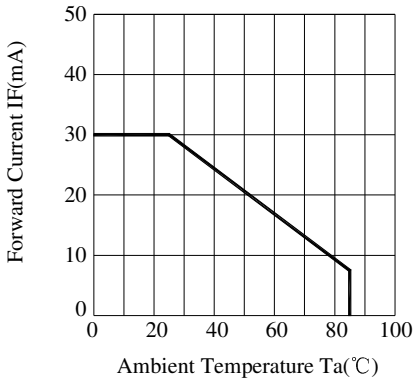


Fig.6 Forward Current Derating Curve

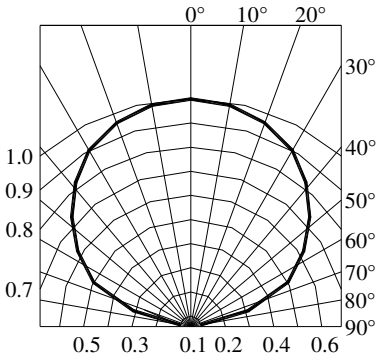


Fig.7 Relative Intensity vs.Angle

● Super Amber Typical Electro-Optical Characteristics Curves

(25℃ Ambient Temperature Unless Otherwise Noted)

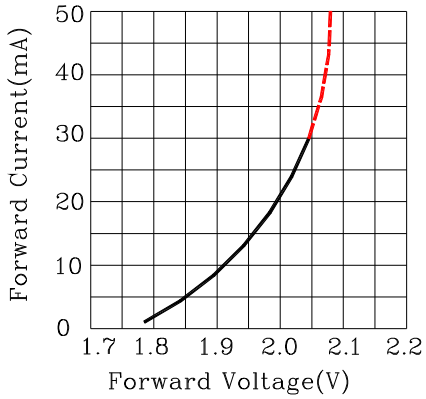


Fig.2 Forward Current vs.Forward Voltage

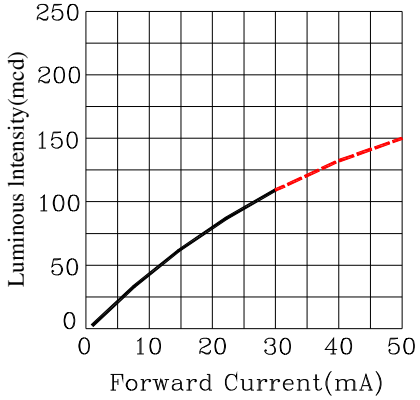


Fig.3 Luminous Intensity vs.Forward Current

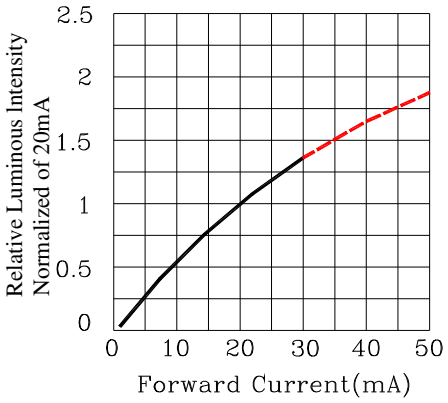


Fig.4 Relative Luminous Intensity vs.Forward Current

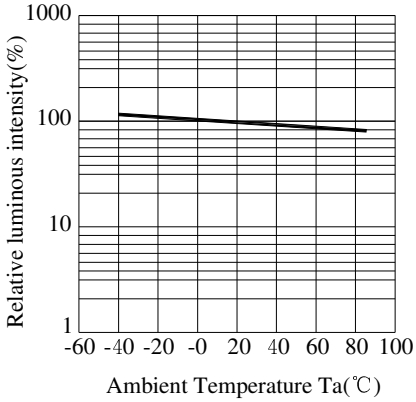


Fig.5 Luminous Intensity vs.Ambient Temperature

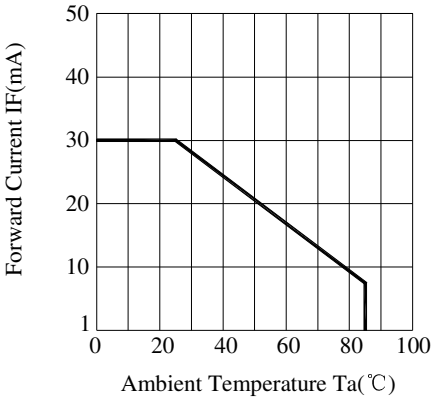


Fig.6 Forward Current Derating Curve

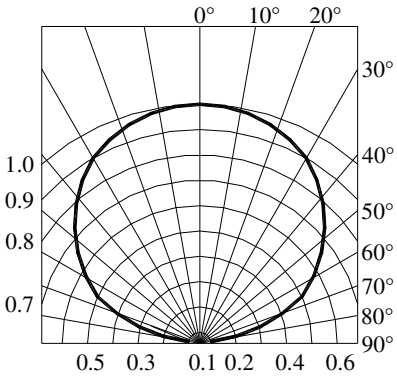


Fig.7 Relative Intensity vs.Angle

● Label Explanation

ITEM CODE:PARRA LIGHT

PART NO: L-S115KGKFCT-FX

IV --- Luminous Intensity Code

LOT NO: EM S L 12 09 0110
A B C D E F

A---EM: Emos Code

B---S:SMD

L---Local

D---Year

E---Month

F---SPEC.

PACKING QUANTITY OF BAG :

3000pcs for 150、170、110、155、115 series

4000pcs for 191 series

5000pcs for 192 series

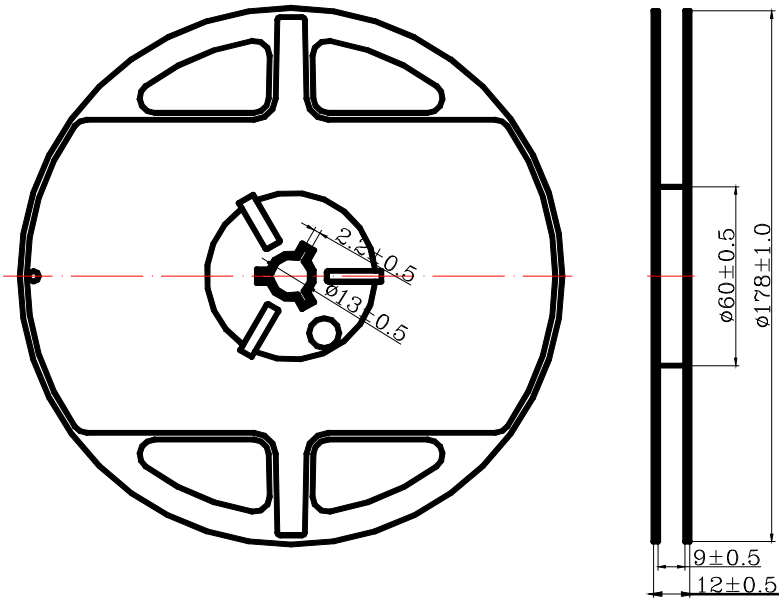
DATE CODE：2012 09 10
G H I

G--- Year

H--- Month

I --- Day

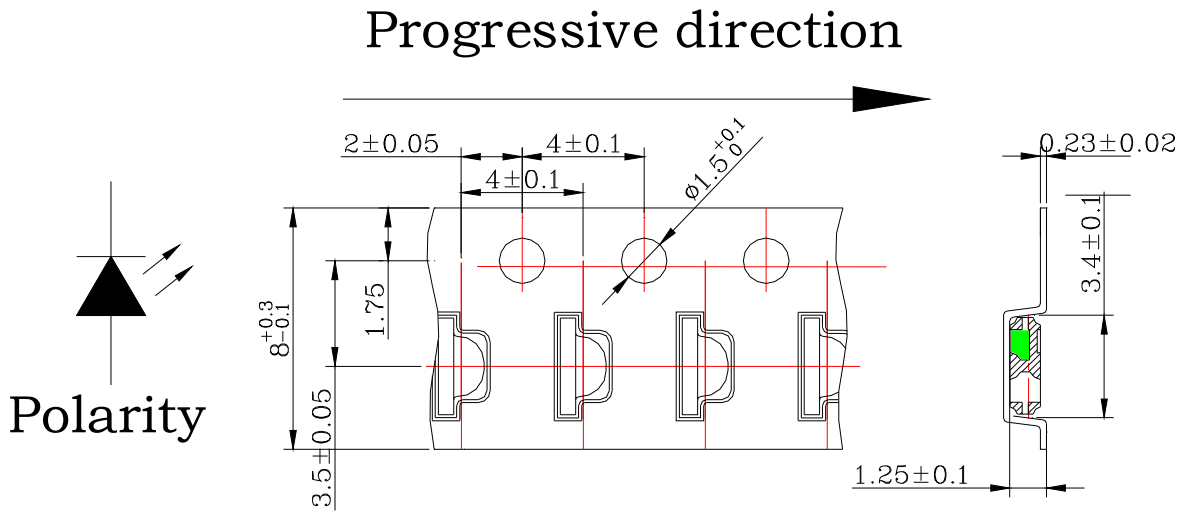
- Reel Dimensions



Notes:

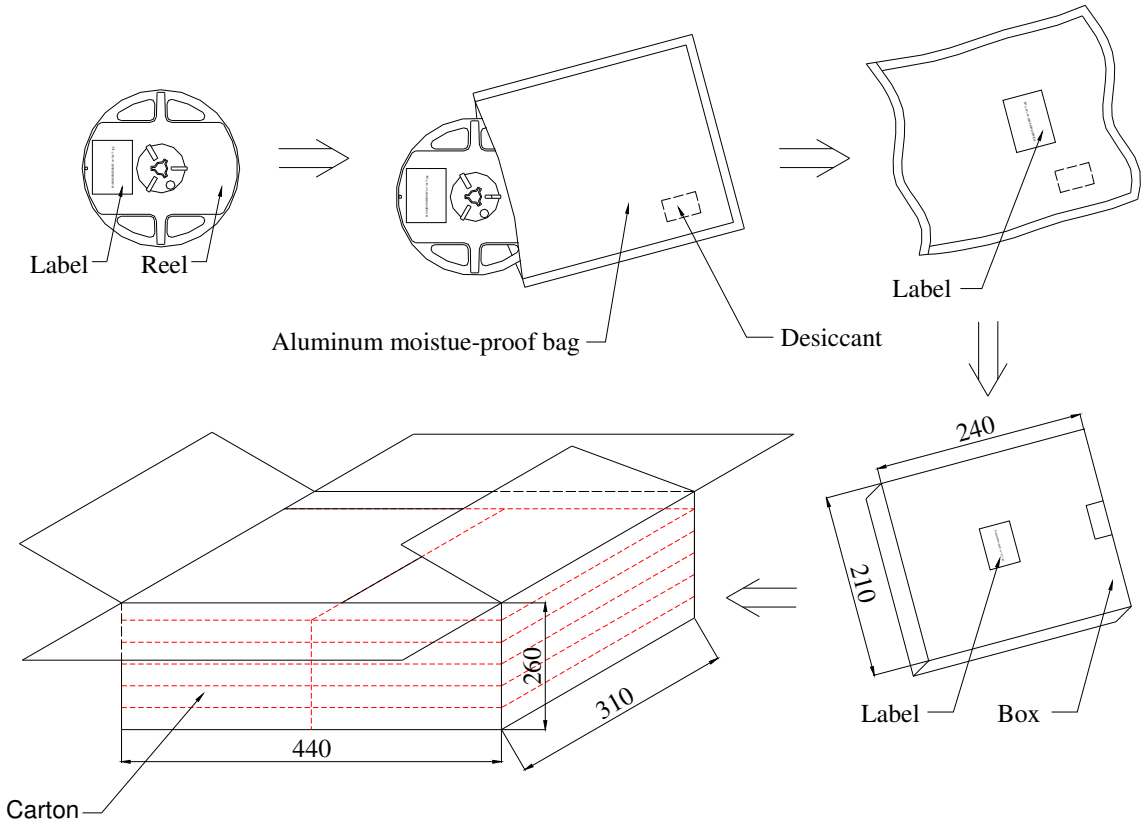
1. Taping Quantity: 3000pcs.
2. The tolerances unless mentioned is ±0.1mm, Angle ±0.5° , Unit: mm.

- Package Dimensions Of Tape And Reel



Notes : All dimensions are in millimeters.

Moisture Resistant Packaging



Notes : One reel in a bag, six bag in a inner box, six inner boxes in a carton. Unit : mm.

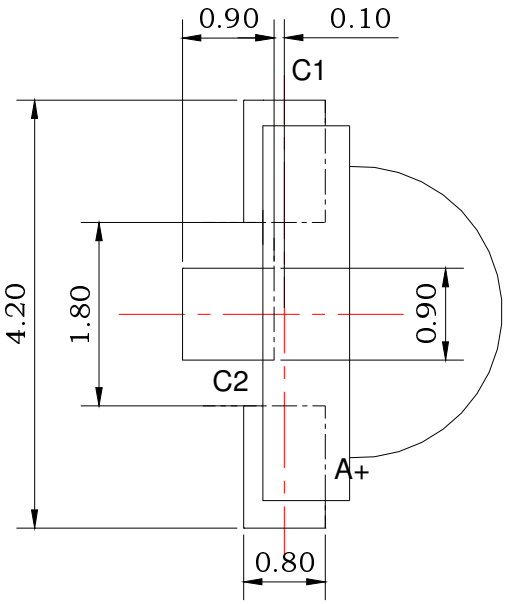
- Cleaning

  ∗ If cleaning is required , use the following solutions for less than 1 minute and less than 40℃.

  ∗ Appropriate chemicals: Ethyl alcohol and isopropyl alcohol.

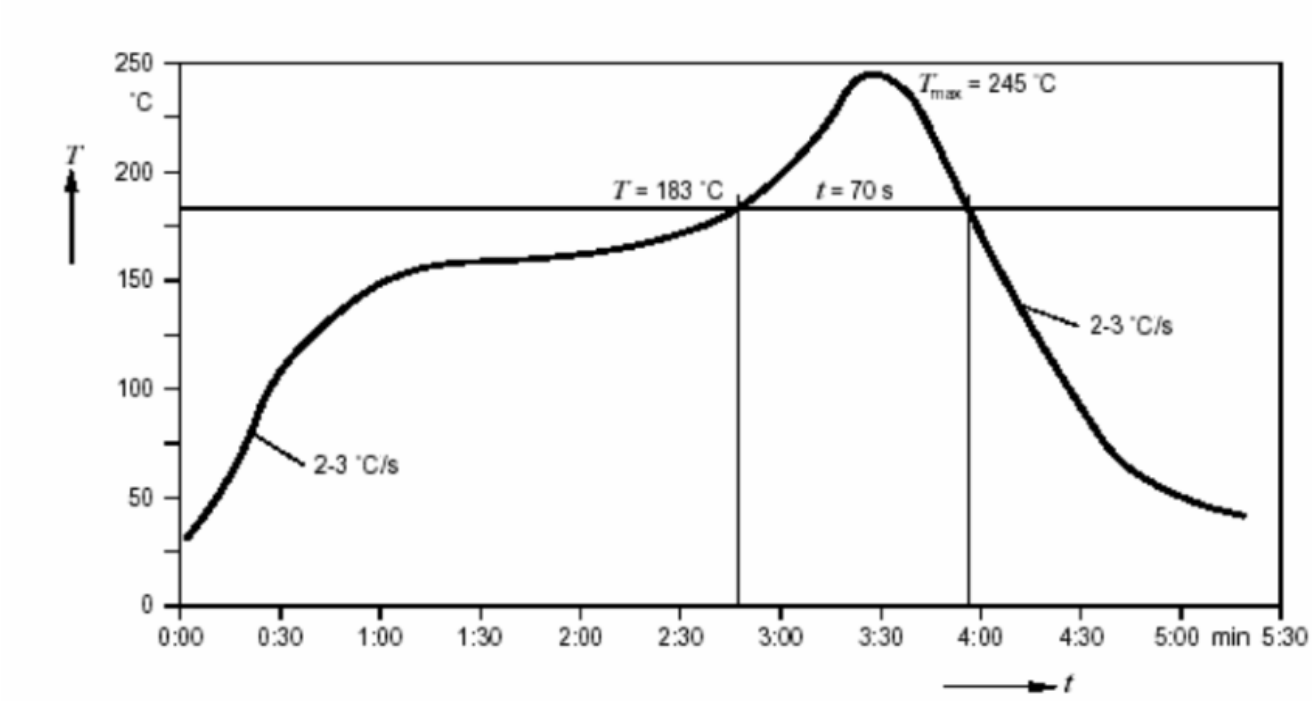
  ∗ Effect of ultrasonic cleaning on the LED resin body differs depending on such factors as the oscillator output, size of PCB and LED mounting method. The use of ultrasonic cleaning should be enforced at proper output after confirming there is no problem.

- Suggest Soldering Pad Dimensions

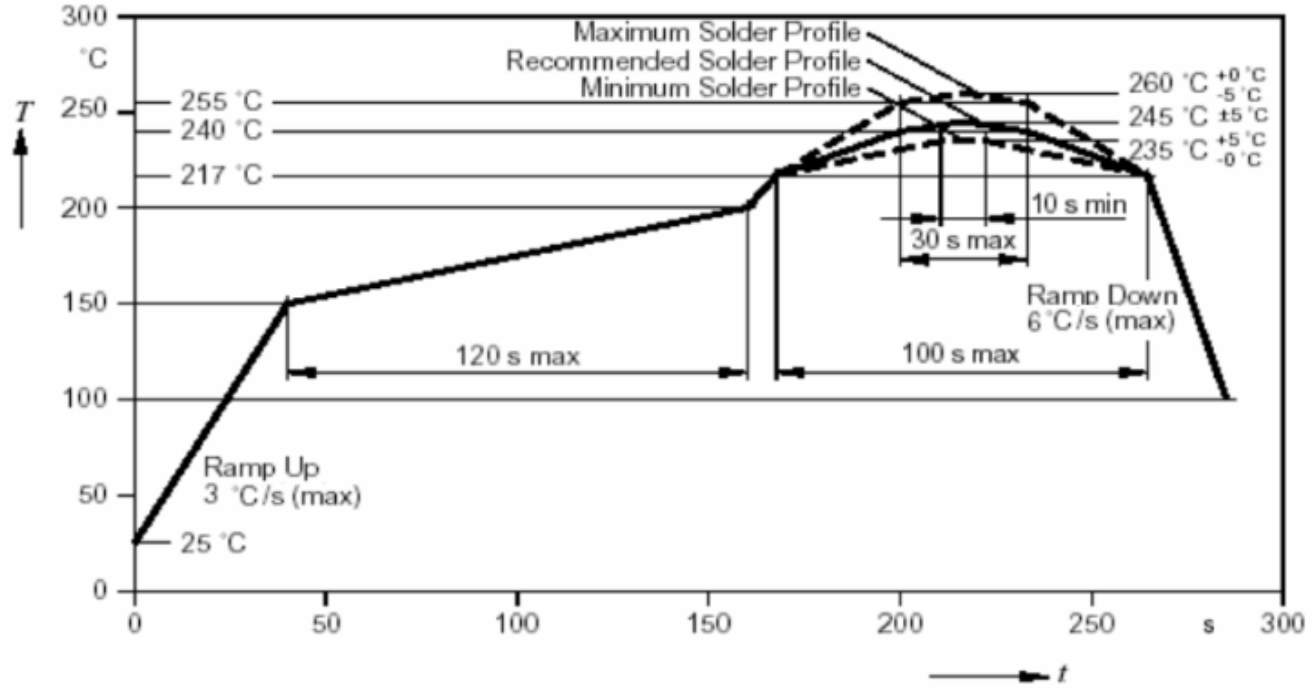


Direction of PWB camber
and go to reflow furnace

- Suggest Sn/Pb IR Reflow Soldering Profile Condition:



- Suggest Pb-Free IR Reflow Soldering Profile Condition:



● Bin Code List

Luminous Intensity(IV), Unit:mcd@20mA					
Super Green (a chip)			Super Amber (b chip)		
Bin Code	Min	Max	Bin Code	Min	Max
N	28.0	45.0	P	45.0	71.0
P	45.0	71.0	Q	71.0	112.0
Q	71.0	112.0	R	112.0	180.0

Tolerance of each bin are±15%

Dominant Wavelength (Hue),Unit: nm@20mA					
Super Green (a chip)			Super Amber (b chip)		
Bin Code	Min	Max	Bin Code	Min	Max
GB	570.0	573.0	OA1	600	603
GC	573.0	576.0	OA2	603	606
			OB1	606	609
			OB2	609	612

Tolerance of each bin are±1nm

● CAUTIONS

1.Application Limitation :

The LED's described here are intended to be used for ordinary electronic equipment (such as office equipment, communication equipment and household application).Consult PARA's sales in advance for information on application in which exceptional quality and reliability are required, particularly when the failure or malfunction of the LED's may directly jeopardize life or health (such as airplanes, automobiles, traffic control equipment, life support system and safety devices).

2.Storage :

Do not open moisture proof bag before the products are ready to use.

Before opening the package: The LEDs should be kept at 30℃ or less and 90%RH or less.

After opening the package: The LED's floor life is 1 year under 30℃ or less and 60% RH or less. If unused LEDs remain, it should be stored in moisture proof packages.

If the moisture absorbent material (silica gel) has faded away or the LEDs have exceeded the storage time, baking treatment should be performed using the following conditions.

Baking treatment: 60±5℃ for 24 hours

3.Soldering(Standard Process) :

Do not apply any stress to the lead frame during soldering while the LED is at high temperature.
Recommended soldering condition.

Reflow Soldering :

Pre-heat 120~150°C, 120sec. MAX., Peak temperature : 240°C Max. Soldering time : 10 sec Max.

Soldering Iron : (Not recommended)

Temperature 300°C Max., Soldering time : 3 sec. Max.(one time only), power dissipation of iron : 20W Max. use SN60 solder of solder with silver content and don't to touch LED lens when soldering.

Wave soldering :

Pre-heat 100°C Max, Pre-heat time 60s Max, Solder wave 260°C Max, Soldering time 5 sec. Max. preformed consecutively cooling process is required between 1st and 2nd soldering processes.

4. Lead-Free Soldering

For Reflow Soldering :

1、Pre-Heat Temp : 150-180℃,120sec.Max.

2、Soldering Temp : Temperature Of Soldering Pot Over 230℃,40sec.Max.

3、Peak Temperature : 260℃， 5sec.

4、Reflow Repetition : 2 Times Max.

5、Suggest Solder Paste Formula 93.3 Sn/3.1 Ag/3.1 Bi /0.5 Cu

For Soldering Iron (Not Recommended) :

1、Iron Tip Temp : 350℃ Max.

2、Soldering Iron : 30w Max.

3、Soldering Time : 3 Sec. Max. One Time.

For Dip Soldering :

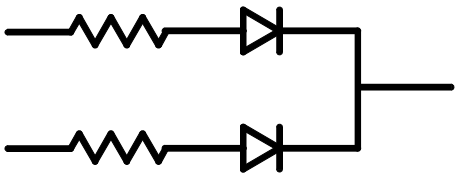
1、Pre-Heat Temp : 150℃ Max. 120 Sec. Max.

2、Bath Temp : 265℃ Max.

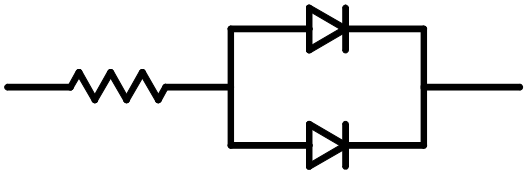
3、Dip Time : 5 Sec. Max.

5. Drive Method

Circuit model A



Circuit model B



(A)Recommended circuit.

(B)The difference of brightness between LED`s could be found due to the Vf-If characteristics of LED.

6.Reliability Test

Classification	Test Item	Test Condition	Reference Standard
Endurance Test	Operation Life	Ta= Under Room Temperature As Per Data Sheet Maximum Rating *Test Time= 1000HRS (-24HRS,+72HRS)*@20mA.	MIL-STD-750D:1026 (1995) MIL-STD-883D:1005 (1991) JIS C 7021:B-1 (1982)
	High Temperature High Humidity Storage	IR-Reflow In-Board, 2 Times Ta= 65±5℃,RH= 90～95% *Test Time= 1000HRS±2HRS	MIL-STD-202F:103B(1980) JIS C 7021:B-11(1982)
	High Temperature Storage	Ta= 105±5℃ Test Time= 1000HRS (-24HRS,72HRS)	MIL-STD-883D:1008 (1991) JIS C 7021:B-10 (1982)
	Low Temperature Storage	Ta= -55±5℃ *Test Time=1000HRS (-24HRS,72H RS)	JIS C 7021:B-12 (1982)
Environmental Test	Temperature Cycling	105±5℃ -55±5℃ 10mins 10mins 100 Cycles	MIL-STD-202F:107D (1980) MIL-STD-750D:1051(1995) MIL-STD-883D:1010 (1991) JIS C 7021:A-4(1982)
	Thermal Shock	IR-Reflow In-Board, 2 Times 105±5℃ -55℃±5℃ 10mins 10mins 100 Cycles	MIL-STD-202F:107D(1980) MIL-STD-750D:1051(1995) MIL-STD-883D:1011 (1991)
	Solder Resistance	Tsol= 260 ± 5℃ Dwell Time= 10 ± 1sec	MIL-STD-202F:210A(1980) MIL-STD-750D:2031(1995) JIS C 7021:A-1(1982)
	Solder ability	Tsol= 235 ± 5℃ Immersion time 2±0.5 sec Immersion rate 25±2.5 mm/sec Coverage ≧95% of the dipped surface	MIL-STD-202F:208D(1980) MIL-STD-750D:2026(1995) MIL-STD-883D:2003(1991) IEC 68 Part 2-20 JIS C 7021:A-2(1982)

7.Others:

The appearance and specifications of the product may be modified for improvement without notice.

SURFACE MOUNT DEVICE LED

Part No. : SZS115KGKFCT

● PART NO. SYSTEM :

SZ S 115X1X2 X X - X X X X

XXXX	**Special specification for customer**
-	**T : Taping for 7 inch reel** **TC : Taping for 13 inch reel** **TH : IV half binning** **TP : Wavelength binning**
X	**Lens color** **C : Water Clear** **W : White Diffused** **T : Color Transparent** **D : Color Diffused**
X	**G : Gap 570nm Green** **Y : GaAsp 585 nm Yellow** **E : GaAsp 620 nm Orange** **SR : GaAlAs 634 nm Red** **KG : AlInGap 570nm Super Green** **KY : AlInGap 590nm Super Yellow** **KF : AlInGap 605nm Super Amber** **KR : AlInGap 630 nm Super Red** **KD : AlInGap 639 nm Deep Red** **LB : InGaN 470nm Blue** **LG: InGaN 525nm Green**
X	**0 : Single chip** **1 / 2 : Super thin single chip** **5 / 6 : Dual chip** **F : Three chip(Full color)**
X	**150 : 1206 1.1T Type** **155 : 1210 1.1T Type** **170 : 0805 0.8T Type** **191 : 0603 0.6T Type** **192 : 0603 0.4T Type** **195 : 0603 0.6T Type** **110 : 1206 1.0T Type** **115 : 1206 1.0T Type**
S	**C : Top View Type** **S : Side View Type**